Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

- Small Size
- · Passivated Die for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- Available in Two Package Styles
 Surface Mount Lead Form Case 369A
 Miniature Plastic Package Straight Leads Case 369

ORDERING INFORMATION

- To Obtain "DPAK" in Surface Mount Leadform (Case 369A)
 Shipped in Sleeves No Suffix, i.e. MCR12DCN
 Shipped in 16 mm Tape and Reel Add "T4" Suffix to Device Number, i.e. MCR12DCNT4
- To Obtain "DPAK" in Straight Lead Version (Case 369) Shipped in Sleeves Add "-1" Suffix to Device Number, i.e. MCR12DCN-1

MCR12DCM MCR12DCN

Motorola Preferred Devices

SCRs 12 AMPERES RMS 600 thru 800 VOLTS



CASE 369A-13 STYLE 4

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating		Symbol	Value	Unit
Peak Repetitive Off–State Voltage (1) Peak Repetitive Reverse Voltage (T _J = -40 to 125°C)	MCR12DCM MCR12DCN	VDRM VRRM	600 800	Volts
On–State RMS Current (All Conduction Angles; T _C = 90°C)		^I T(RMS)	12 SG.GV	Amps
Average On–State Current (All Conduction Angles; T _C = 90°C)	1800	I _{T(AV)}	7.6	
Peak Non–Repetitive Surge Current (One Half Cycle, 60 Hz, T _J = 125°C)	J. 10	I _{TSM}	100	
Circuit Fusing Consideration (t = 8.3 msec)		l ² t	41	A ² sec
Peak Gate Power (Pulse Width ≤ 10 μsec, T _C = 90°C)		Р _{GМ}	5.0	Watts
Average Gate Power (t = 8.3 msec, T _C = 90°C)		P _{G(AV)}	0.5	
Peak Gate Current (Pulse Width ≤ 10 μsec, T _C = 90°C)		IGM	2.0	Amps
Operating Junction Temperature Range		TJ	-40 to 125	°C
Storage Temperature Range	180 7	T _{stg}	-40 to 150	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance — Junction to Case — Junction to Ambient — Junction to Ambient (2)	R _θ JC R _θ JA R _θ JA	2.2 88 80	°C/W
Maximum Lead Temperature for Soldering Purposes (3)	Tı	260	°C

⁽¹⁾ V_{DRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the device are exceeded.

(2) Surface mounted on minimum recommended pad size.

(3) 1/8" from case for 10 seconds.

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referred devices are Motorola recommended choices for future use and best overall value.



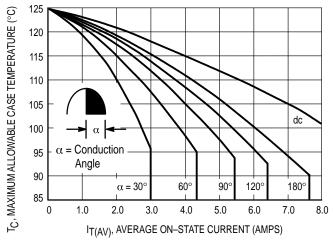
ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
Peak Forward Blocking Current Peak Reverse Blocking Current	IDRM IRRM				mA
$(V_{AK} = Rated V_{DRM} \text{ or } V_{RRM}, \text{ Gate Open})$ $T_{J} = 25^{\circ}C$ $T_{J} = 125^{\circ}C$		_ _		0.01 5.0	
Peak On–State Voltage ⁽¹⁾ (I _{TM} = 24 A)	V _{TM}	_	1.4	2.1	Volts
Gate Trigger Current (Continuous dc) $ (V_D = 12 \text{ V}, \text{ R}_L = 100 \ \Omega, \text{ T}_J = 25^{\circ}\text{C}) \\ (V_D = 12 \text{ V}, \text{ R}_L = 100 \ \Omega, \text{ T}_J = -40^{\circ}\text{C}) $	^I GT	2.0	7.0 —	20 40	mA
Gate Trigger Voltage (Continuous dc) $ (V_D = 12 \text{ V}, \text{ R}_L = 100 \ \Omega, \text{ T}_J = 25^{\circ}\text{C}) \\ (V_D = 12 \text{ V}, \text{ R}_L = 100 \ \Omega, \text{ T}_J = -40^{\circ}\text{C}) \\ (V_D = 12 \text{ V}, \text{ R}_L = 100 \ \Omega, \text{ T}_J = 125^{\circ}\text{C}) $	Vgт	0.5 — 0.2	0.65 — —	1.0 2.0 —	Volts
Holding Current $(V_D = 12 \text{ V, } I_T = 200 \text{ mA, } T_J = 25^{\circ}\text{C})$ $(V_D = 12 \text{ V, } I_T = 200 \text{ mA, } T_J = -40^{\circ}\text{C})$	Ιн	4.0 —	22 —	40 80	mA
Latching Current $(V_D = 12 \text{ V, I}_G = 20 \text{ mA, T}_J = 25^{\circ}\text{C})$ $(V_D = 12 \text{ V, I}_G = 40 \text{ mA, T}_J = -40^{\circ}\text{C})$	lL	4.0 —	22 —	40 80	mA

DYNAMIC CHARACTERISTICS

Characteristics	Symbol	Min	Тур	Max	Unit
Critical Rate of Rise of Off–State Voltage	dv/dt				V/μs
$(V_D = Rated V_{DRM}, Exponential Waveform, Gate Open, T_J = 125^{\circ}C)$		50	200	_	

⁽¹⁾ Pulse Test; Pulse Width \leq 2.0 msec, Duty Cycle \leq 2%.



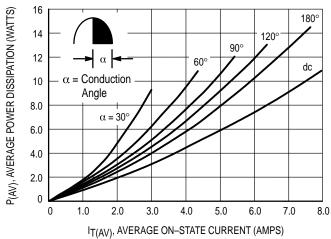
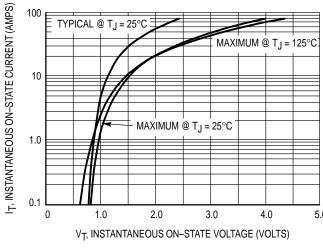


Figure 1. Average Current Derating

Figure 2. On-State Power Dissipation





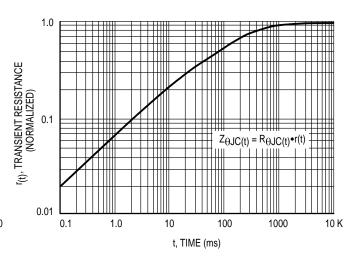


Figure 4. Transient Thermal Response

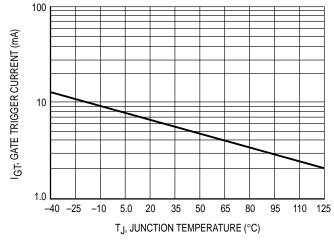


Figure 5. Typical Gate Trigger Current versus **Junction Temperature**

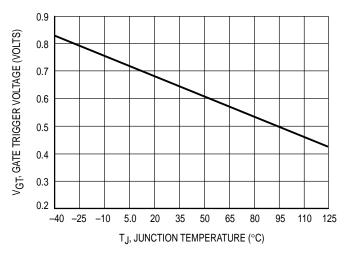


Figure 6. Typical Gate Trigger Voltage versus **Junction Temperature**

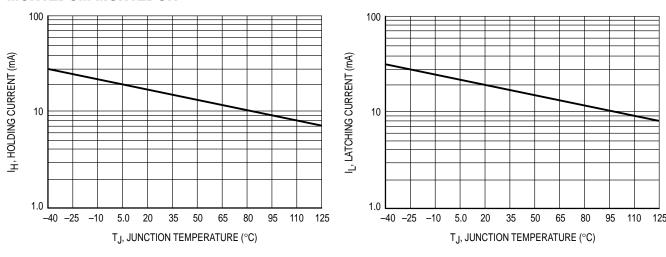


Figure 7. Typical Holding Current versus Junction Temperature

Figure 8. Typical Latching Current versus Junction Temperature

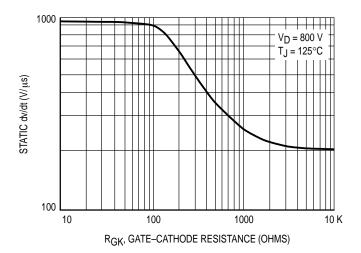
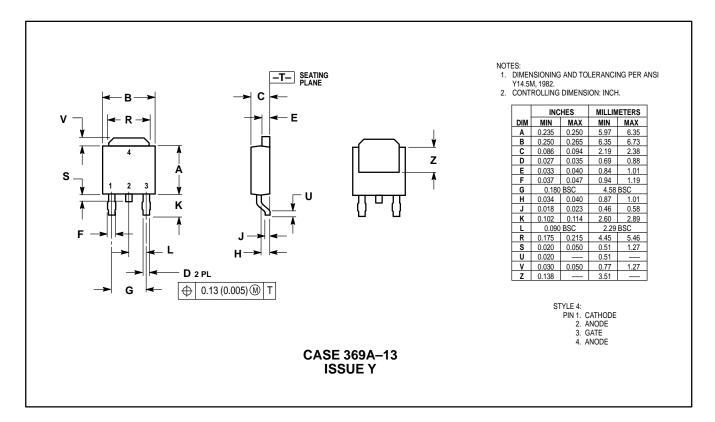


Figure 9. Exponential Static dv/dt versus Gate–Cathode Resistance

PACKAGE DIMENSIONS



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